Structural and Optical Properties of Chalcogenide WS₂ Thin Film



267

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1 Introduction

The transition metal dichalcogenide compounds are found very useful in a wide range of applications these days [1]. Among the known 2D transition metal dichalcogenides, the tungsten disulphide (WS₂) material possesses high electron mobility owing to the decreased effective mass of electrons in WS₂ [2]. WS₂ exhibits a layered structure. The molecules in the layers of WS₂ are held together by weak van der Waals interactions within each layer of WS₂, there are strong covalent bonds between tungsten and sulfur atoms. The covalent bonds hold the atoms together within each layer, forming a hexagonal lattice [3]. Due to low toxicity, WS₂ can be used safely in a variety of applications including optoelectronic and light-sensing devices [4]. Thin films of WS₂ possess a polycrystalline structure with a hexagonal phase. The WS₂ structure consists of three layers, with a tungsten (W) layer sandwiched between two Sulphur (S) layers. The widely studied transition metal

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